

Maximum Ratings – TOTAL DEVICE (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1.5	W
Thermal Resistance, Junction to Ambient	R _{θJA}	85	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Maximum Ratings – P-CHANNEL MOSFET – Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	-20	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 5)	I _D	-2.9	A
Pulsed Drain Current (Note 6)	I _{DM}	-10	A

Maximum Ratings – SBR – D1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	20	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	14	V
Average Rectified Output Current	I _O	1	A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	3	A

Electrical Characteristics – P-CHANNEL MOSFET – Q1 (@T_A = +25°C, unless otherwise specified.)

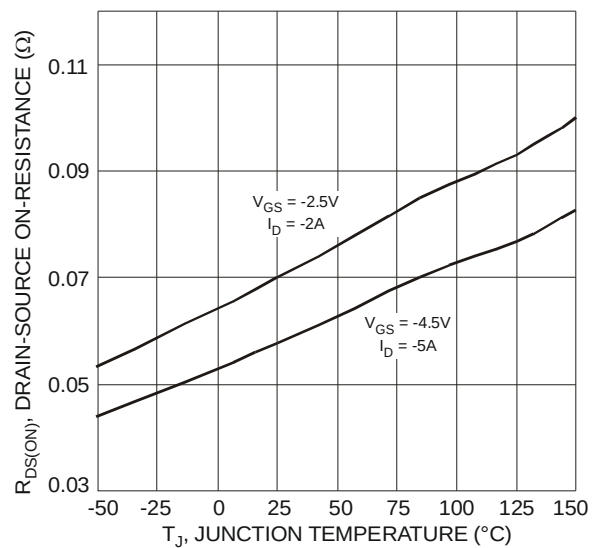
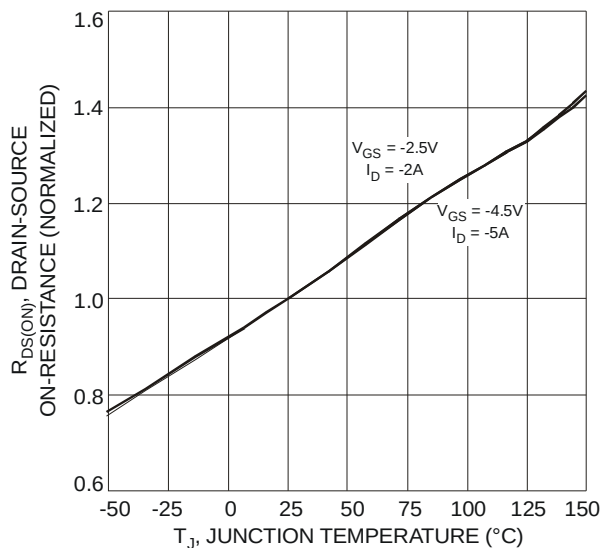
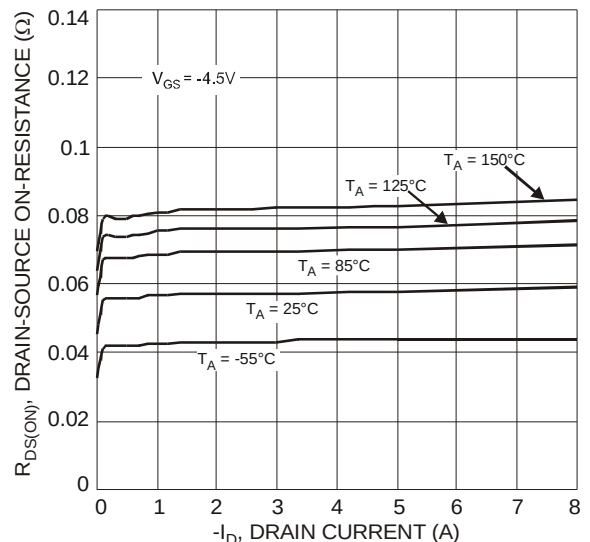
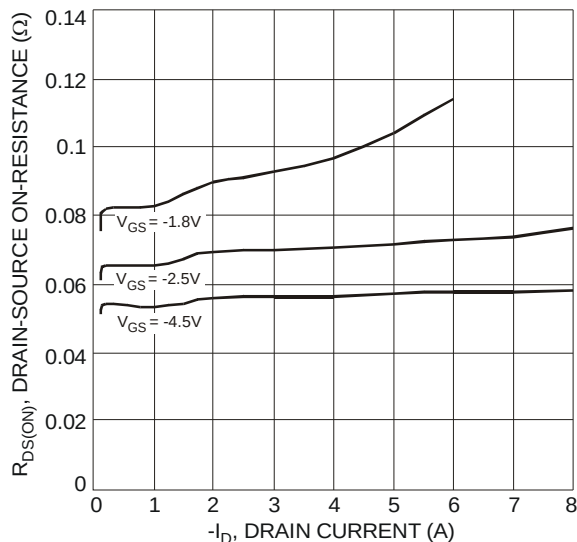
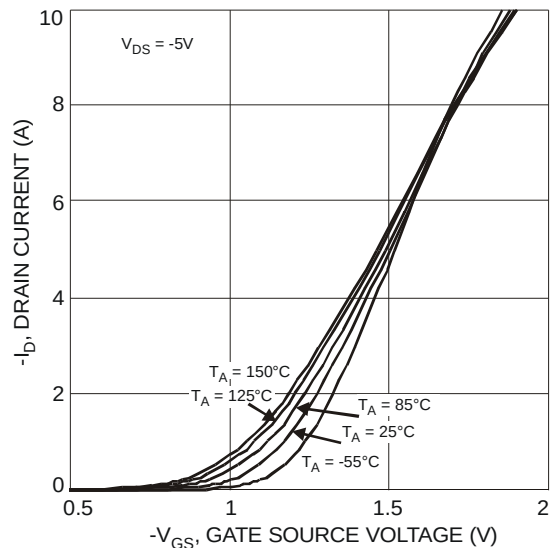
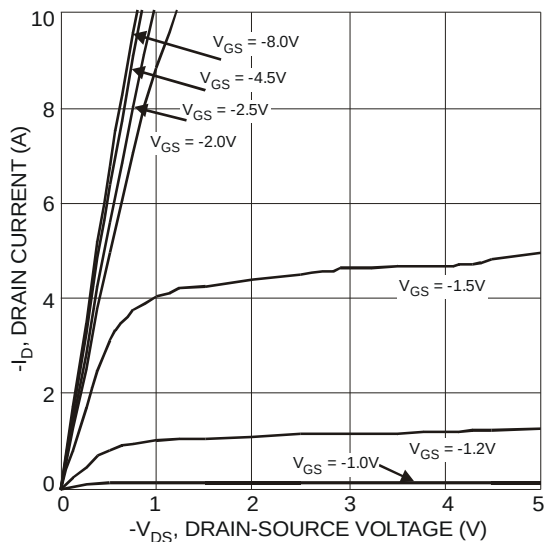
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	—	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	V _{DS} = -20V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100 ±800	nA	V _{GS} = ±8V, V _{DS} = 0V V _{GS} = ±12V, V _{DS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	-0.45	—	-1.3	V	V _{DS} = V _{GS} , I _D = -250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	70	95	mΩ	V _{GS} = -4.5V, I _D = -2.8A
		—	84	120		V _{GS} = -2.5V, I _D = -2.0A
		—	100	150		V _{GS} = -1.8V, I _D = -1.0A
Forward Transfer Admittance	Y _{fs}	—	8	—	S	V _{DS} = -5V, I _D = -2.8A
Diode Forward Voltage (Note 7)	V _{SD}	—	0.42	-1.2	V	V _{GS} = 0V, I _S = -1.0A
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	—	632	—	pF	V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	65	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	54	—	pF	

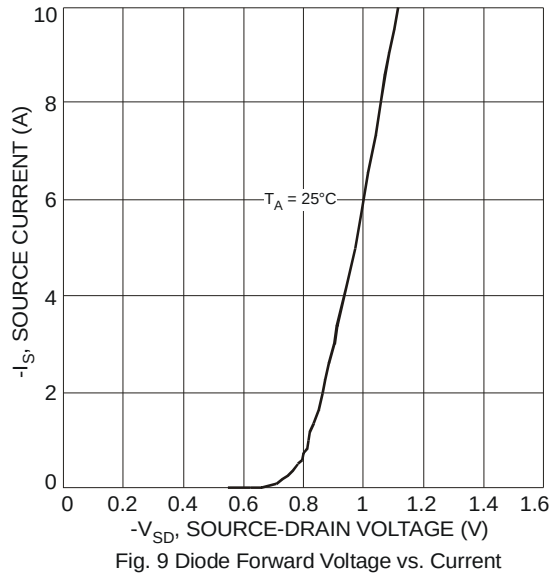
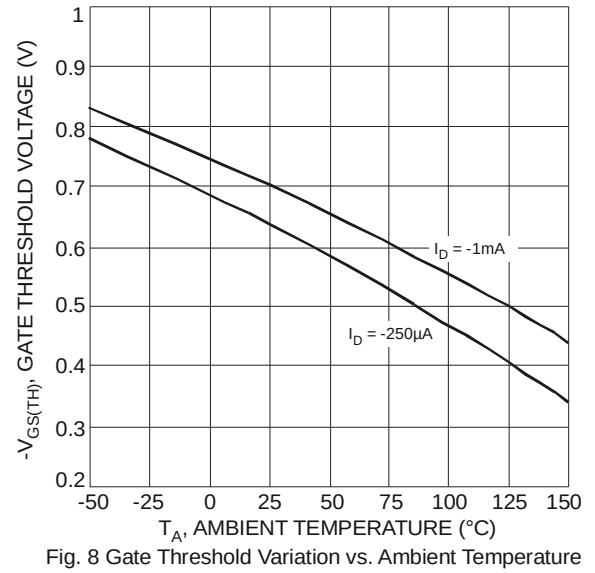
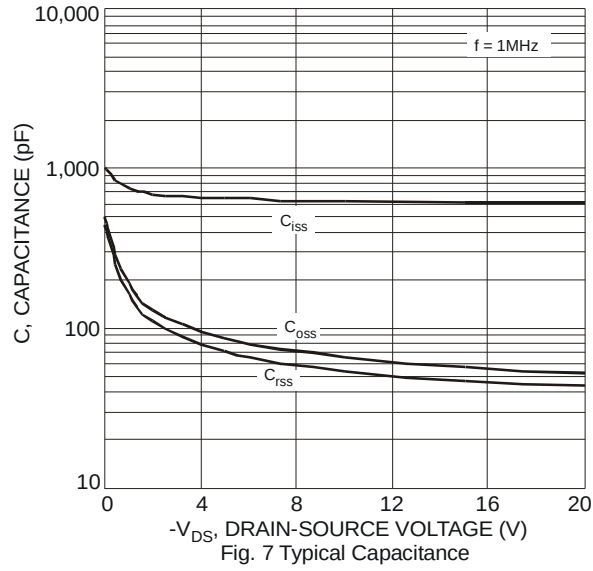
Electrical Characteristics – SBR – D1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	V _{(BR)R}	20	—	—	V	I _R = 1mA
Forward Voltage	V _F	—	—	0.45	V	I _F = 0.5A
		—	—	0.52		I _F = 1.0A
Reverse Current (Note 7)	I _R	—	—	80	μA	V _R = 20V

- Notes:
5. Device mounted on FR-4 PCB, on minimum recommended, 2oz Copper pad layout.
 6. Repetitive rating, pulse width limited by junction temperature.
 7. Short duration pulse test used to minimize self-heating effect.

Q1, P-CHANNEL MOSFET





D1, SBR

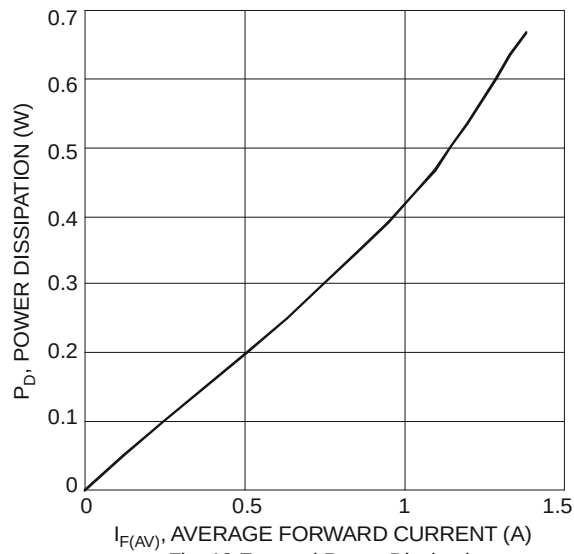


Fig. 10 Forward Power Dissipation

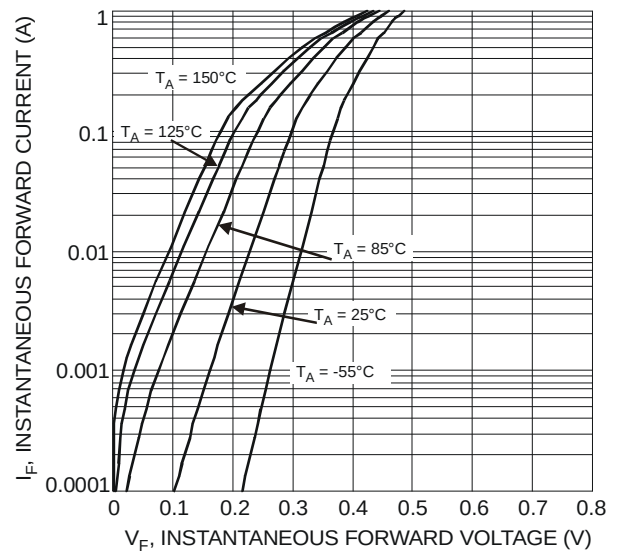


Fig. 11 Typical Forward Characteristics

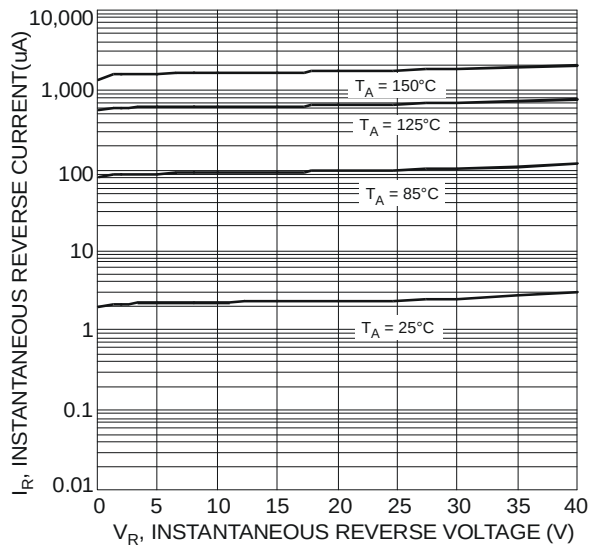


Fig. 12 Typical Reverse Characteristics

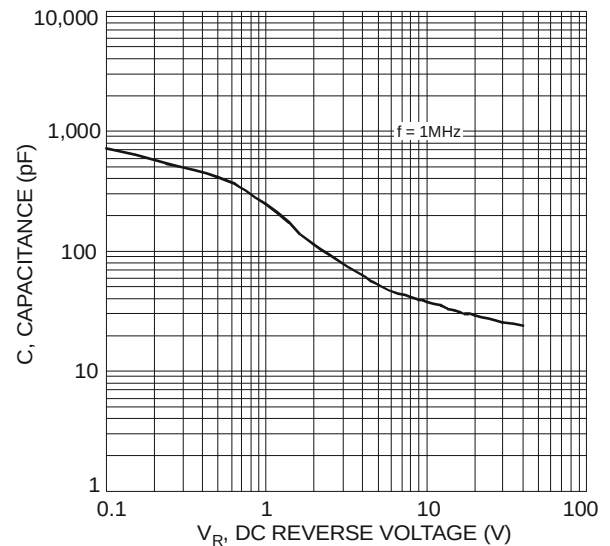


Fig. 13 Total Capacitance vs. Reverse Voltage

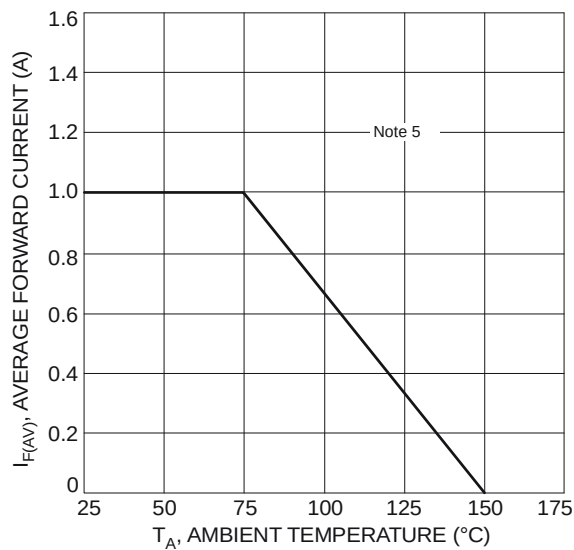


Fig. 14 Forward Current Derating Curve

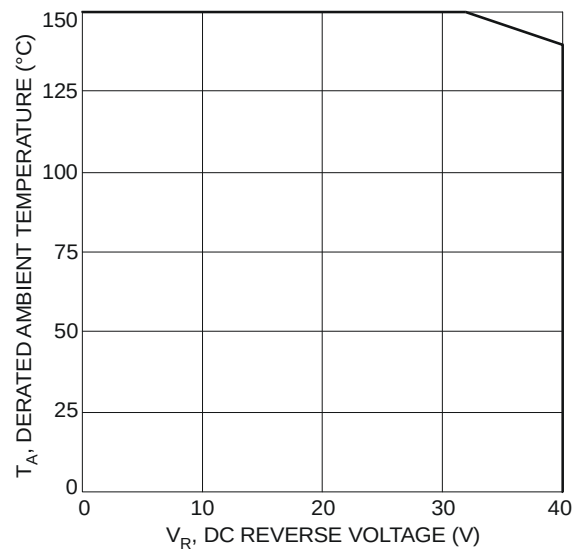
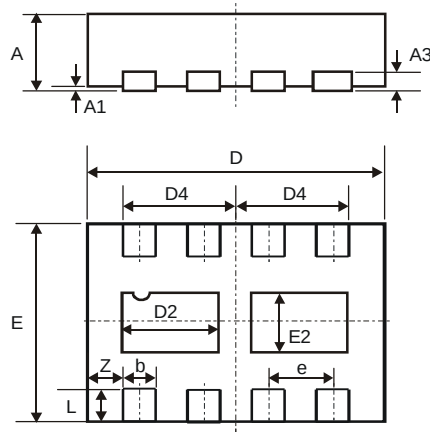


Fig. 15 Operating Temperature Derating

Package Outline Dimensions

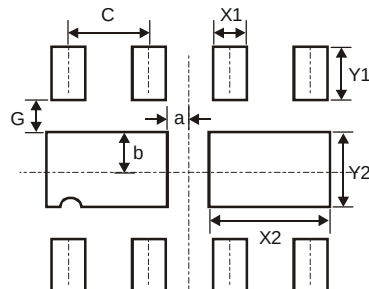
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



U-DFN3020-8 Type B			
Dim	Min	Max	Typ
A	0.77	0.83	0.80
A1	0	0.05	0.02
A3	-	-	0.15
b	0.25	0.35	0.30
D	2.95	3.075	3.00
D2	0.82	1.02	0.92
D4	1.01	1.21	1.11
e	-	-	0.65
E	1.95	2.075	2.00
E2	0.43	0.63	0.53
L	0.25	0.35	0.30
Z	-	-	0.375
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
a	0.09
b	0.365
C	0.65
G	0.285
X1	0.4
X2	1.12
Y1	0.5
Y2	0.73

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